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_	First Named Inventor	Leonard Forbes	
1	Serial No.	10/808,059	REPLY UNDER 37 C.F.R. §1.116 –
	Filing Date	March 24, 2004	EXPEDITED PROCEDURE – TECHNOLOGY CENTER 2800
M	Group Art Unit	2814	TECHNOLOGI CENTER 2000
	Examiner Name	Marcos D. Pizarro Crespo	
	Confirmation No.	4221	
	Attorney Docket No.	400.285US01	

Title: NROM MEMORY DEVICE WITH HIGH-PERMITTIVITY GATE DIELECTRIC FORMED BY THE LOW TEMPERATURE OXIDIZATION OF METALS

Mail Stop: AF Commissioner for Patents P.O. Box 1450

Alexandria, VA 22313-1450

In response to the Final Office Action mailed October 3, 2006, please consider the following: